

Currents induced by domain wall motion in thin ferromagnetic wires

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Historically the role of eddy currents in the motion of Bloch walls has been extensively studied. In contrast the direct interaction of currents with such a moving wall has received very little attention. However recently it has been shown that a wall can be displaced by the effects of a current alone, a fact which is important to the development of spintronics. We report here that such a moving wall within an itinerant ferromagnet constitutes a seat of electromotive-force (or more accurately a spin-motive-force) which induces a current flow in an external circuit. While an external magnetic field is the most evident means by which to induce Bloch wall motion, it is not the only possibility and the forces intrinsic to certain geometries imply that the state of a spintronics memory device might be read via this mechanism using currents alone and that power amplification of spin polarized pulses is possible. An estimate of the induced current shows it to be technologically useful.

Spintronic devices have great technological promise but represent a challenging problem at both an applied and fundamental level. It has been shown both theoretically (1, 2) and exper-

imentally (3, 4) that a Bloch wall might be driven down a nano-sized wire through the effects of currents alone. Using the fact that such a wall can be pinned at some chosen point in the wire, this effect can be used, e.g., to write bits into a memory element. It is usually envisaged that the state of such a device be read using the GMR effect (4). We demonstrate here, when a Bloch wall moves, it induces a spin current and hence, for spin polarized conduction electrons, constitutes a seat of electro-motive-force (emf). More accurately the moving wall constitutes a spin-motive-force (smf). This is the elusive (5) equivalent of an emf but which drives spin rather than charge currents. The application of a *static* magnetic field is the most evident fashion by which to induce Bloch wall motion and it is an interesting curiosity that an emf/smf can be produced by a *time independent* magnetic field. It is also known (6) that a closed Bloch wall will tend to collapse under its own surface tension. The fact that a wall will move to reduce its total energy, also implies that in restricted geometries it will suffer a force. We will describe how such effects permit the state of a memory device to be not only written but also read *directly* using uniquely currents. This is of appreciable technological importance.

Corresponding to Faraday's law, the elementary definition of an emf is $\mathcal{E} = \oint (\mathbf{f} \cdot d\mathbf{s})$ where $\mathbf{f} = (e)\mathbf{E} + \nabla \times \mathbf{B}$ is the force on the charge e carriers. Here \mathbf{E} and \mathbf{B} are the electric and magnetic fields respectively. Analyzed here is an unappreciated additional source of an emf. Again it is an elementary fact that, e.g., in a Stern-Gerlach experiment, there is a force $\mathbf{f}_s = (\nabla \cdot \nabla) \sim \mathbf{B}$; where \sim is the spin magnetic moment. In the current situation \mathbf{f}_s is due to a finite $\nabla \cdot \nabla$ rather than a $\nabla \cdot \mathbf{B} = \nabla \cdot \mathbf{B}$ and, in particular, occurs because \mathbf{B} changes direction within a Bloch wall. Evidently \mathbf{f}_s should be included in the definition of \mathcal{E} .

The central results are first deduced using conservation principles. The wire geometry is shown in Fig. 1. The anisotropy energy is such that the magnetization far from the Bloch wall points along the wire and this is taken to be the z-direction. In order to exert a force on the wall, a static magnetic field \mathbf{B} is applied along the same direction. For an itinerant ferromagnet, in ad-

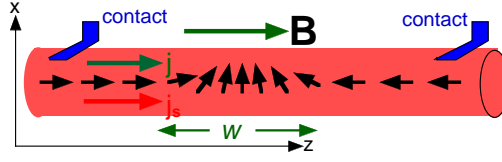


Figure 1: Far from the central wall the spins point along the easy axis taken to be the z -direction. There is also a magnetic field B in the z -direction. The wall lies in the $x-z$ -plane. The conduction electrons carry spin j_s and charge currents j .

dition to the local-magnetic-moments which constitute the wall, are conduction electrons which can carry a current. It is assumed initially that there is conservation of, J_z , the z -component of the *total* angular momentum. The motion of the wall constitutes a local-moment spin current and the conservation of J_z requires an equal and opposite conduction electron spin current. If A_0 is the cross-sectional area, v_c is unit cell volume, S the net spin per site, and v its velocity, then in a time t there are $v t A_0 / v_c$ spins which effectively move towards the wall to constitute a spin current $j_s = S v$. Unlike charge currents, in general, conduction electron spin currents are *not* conserved. However, in an itinerant ferromagnet, the presence of a charge current j_e implies a spin current $j_s = p(j_e/2e)$, where p is the effective magnetic moment per charge carrier. Like the magnetic polarization m , p is a material specific parameter with $p \approx 0.7$ for Permalloy (3). As such, it is a property of the current carrying (thermodynamic) ground state and the relationship $j_s = p(j_e/2e)$ will apply provided that the conduction electrons pass through the wall adiabatically, which must be the case for a large enough width w , Fig. 1. Assuming this to be the case and equating the two spin currents,

$$j_e = \frac{2eS}{p v_c} v; \quad (1)$$

gives a relationship between the charge current and wall velocity which is well known (3). Our assumption of the conservation of angular momentum implies that the wall does not move in the absence of a current, i.e., that there is a coupling between the two sub-systems which will be expanded upon below. This interaction must also conserve energy. The energy decrease of

the wall as it moves must be compensated by an increase in that of the conduction electrons, and which is dissipated in the load. Given that $S g_{\text{B}} B$, where g is the g -factor and μ_{B} is the Bohr magneton, is the Zeeman energy, the local moment energy change, in the time τ is $2S g_{\text{B}} B v \tau = v_c$ while the energy dissipated by the current is $E j_e A \tau$, to give for the emf,

$$E = \frac{p g_{\text{B}} B}{e} : \quad (2)$$

If R is the load resistance then $j_e = I/A_0 = E/A_0 R$ is determined by the emf, i.e., the wall velocity reflects the load resistance. (Ignoring eddy current and relaxation losses.)

The Eqs. 1 and 2 along with their applications to basic devices, detailed below, are the principal results of this Report. However, it is the case these equations result from rather sweeping assumptions about the conservation of angular momentum and energy and which are easily questioned. We have developed a more substantial theory at two levels. What is described in the following amounts to a macroscopic theory. Based upon half-metal limit of the strongly correlated double exchange model, a fully microscopic approach has also been developed. These calculations are reported in the supplementary material in a methods section and substantiate the macroscopic considerations. There is no want of existing theories which might be applicable to this spin transfer problem but none is, in fact, adequate since they cannot address, in a non-perturbative fashion, the two issues behind Eqs. 1-2, i.e., the simultaneous conservation of energy and angular momentum.

It is a fact, which will be exposed below, that the basic coupling, which conserves the angular momentum and energy, is non-perturbative, i.e., does not arise from the interaction which creates the internal exchange field but rather has as its origin the conduction electron kinetic energy. It arises when certain quantum corrections are added to the classical description of the spin degrees of freedom. Magnons are the quantum excitations of a regular ferromagnet. The wavelength $\epsilon = 0$ such magnon is a Goldstone boson which restores the broken symmetry

of a ferromagnet. When a Bloch wall is present, for an infinite uniform system without fields, there is an additional broken symmetry corresponding to specifying the position z_0 of the center of the wall. The restoration of this symmetry is essential to the aforementioned conservation principles. There is a new Goldstone boson b_W^ν , defined below, which has this function. For this reason it is necessary to make a digression into the theory of magnons. As is usual (7), the Holstein-Primakoff transformation $S_{iz} = \hbar (S - b_i^\nu b_i^\nu)$, $S_i^+ = \hbar (2S - b_i^\nu b_i^\nu)^{1/2} b_i^\nu$ $\hbar (2S)^{1/2} b_i^\nu$ is used to quantize the local moment spin, S_i , for site i . In principle, the axes of quantization are arbitrary, *however*, as the standard theory (7) of ferromagnetic magnons well illustrates, *in fact*, if the magnons are to all have positive energies, the local axis of quantization must be taken along the *classical* equilibrium direction, i.e., the direction appropriate in the limit $S \rightarrow \infty$. This local equilibrium direction, for site i , is specified by the Euler angles θ_i and ϕ_i .

The effective Hamiltonian is then, $H = \sum_i V f_i; \phi_i \mathcal{G} + H_t + H_s + H_{ts}$, where the $(B = 0)$ classical energy functional $V f_i; \phi_i \mathcal{G} = \sum_{\langle ij \rangle} J^P \cos(\theta_i - \theta_j) - \sum_i A^P \cos^2 \theta_i$, involves J and A which are the exchange and anisotropy *energy* constants, where the sum $\sum_{\langle ij \rangle}^P$ is over near-neighbors. The kinetic energy of the conduction electrons is H_t , while H_s and H_{ts} are the magnon and interaction Hamiltonians (2). The Bloch wall structure is determined by minimizing this $V f_i; \phi_i \mathcal{G}$ and yields the usual result, $\theta(z) = 2 \cot^{-1} e^{-(z - z_0)/w}$, with $\theta_i = 0$, for a wall centered at z_0 , where the wall width $w = a \frac{J}{2A}^{1/2}$. Here a is the lattice spacing in the z -direction. The local axes used to quantize the local moments changes from $\theta = 0$ to $\theta = \pi$ with increasing z and the wall lies in the $x - z$ -plane, Fig. 1.

A second digression is needed in order to explain the role of the adiabatic theorem. In a discrete model, if t is the hopping matrix element, and if the internal exchange field $J \gg t$, corresponding to a half metal, then it is possible to treat t as a perturbation. Clearly the maximum of exchange energy of a plane corresponds to a maximum in its angular momentum and excited states have energies $\sim J$. In the limit $J \gg t$, electron hopping matrix elements adiabatically

connect these exchange ground states, and for each such ground state the conduction electron spin \mathbf{s} is aligned parallel to the total spin \mathbf{S} (per site). However when the angles between the angular momentum vectors of adjacent planes are small, as in a Bloch wall, the electrons see an almost constant exchange field and the above inequality is certainly too strong. The conduction electron spins rotate by θ as they pass through the wall of width w . They must therefore rotate by an angle $\theta = (a/w) \pi$ per hopping event. These take a time $\tau = \hbar/t$ and therefore the rate of rotation is $\dot{\theta} = (t/\hbar) (a/w) \pi$. In the frame rotating with the electrons, there is an effective transverse field $\hbar \dot{\theta} = g \mu_B B$ (8). These same electrons experience a longitudinal internal exchange field $SJ = g \mu_B B$ and spin-flip transitions are negligible, i.e., the adiabatic theorem is satisfied, if $SJ > \hbar \dot{\theta} = (a/w) \pi \hbar t$ a condition which is well satisfied for, e.g., Permalloy, with $S = 0.5$, $J = 0.3 \text{ eV}$, $t = 1 \text{ eV}$, $w = 200 \text{ nm}$ and $a = 0.35 \text{ nm}$. Since the majority and minority spins are oppositely aligned, the adiabatic condition dictates that

$$\mathbf{s} = \pm \frac{\mathbf{S}}{2S} \quad (3)$$

with the upper (lower) sign for the majority (minority) electron spin direction. Since majority and minority electrons rotate into themselves, their populations are invariant and Eq. 3 correctly implies $\hbar \mathbf{s} \cdot \mathbf{i} = \pm m S = 2S$ (9). The adiabatic transport of the (thermodynamic) ground state through the wall also implies a *fixed* relationship between the spin, \mathbf{j}_s , and charge currents, \mathbf{j}_e . Far from the wall this ground state is such that $\mathbf{j}_s = p \mathbf{j}_e = 2e$, where p is the material dependent constant mentioned above. It is this state which is transported adiabatically through the wall and as a consequence this relationship remains valid even within the wall.

The sought for coupling arises when Schrödinger's equation is written in the frame which rotates with the wall. In this frame there must be a $H_{ts} = (1/2) \int dV (\mathbf{A} \cdot \mathbf{j}_e)$ coupling of an appropriate ($e = c = 1$) vector potential, \mathbf{A} , to the particle current \mathbf{j}_e . This follows since the transformation to the local axes of quantization within the wall corresponds to a gauge

transformation, i.e., if $\psi(z;t)$ is the conduction electron wave function, in the continuum limit, the rotation used to generate a stationary wall, causes $\psi(z;t) \rightarrow e^{i\phi(z)} \psi(z;t)$, where $\phi(z) = \frac{1}{\hbar} \int_{-\infty}^z S_y(z') dz' = \frac{1}{\hbar} \int_{-\infty}^z \hbar S_y(z') dz' = \int_{-\infty}^z S_y(z') dz'$. With $\psi(z;t) = \psi(z)$, the usual transformations of the potentials are $\mathcal{A} \rightarrow \mathcal{A}$, $\tilde{f} \rightarrow f(z)$ and $\mathcal{H} \rightarrow \mathcal{H} + (\partial f / \partial t)$, i.e., $\mathcal{H} \rightarrow \mathcal{H}$ and, in discrete notion, the finite component $A_{iz} = (\partial \phi_i / \partial z) S_{iy}$. Using Eq. 3 to make the replacement $S_{iy} \rightarrow \pm S_{iy} = 2S$ with the upper (lower) sign for the majority (minority) spins, the discrete equivalent of $(1/2) \int dV (\mathcal{A} - \mathcal{A}_n)$ becomes,

$$H_{ts} = p \frac{j_s v_c}{2eS} \sum_i \frac{\partial \phi_i}{\partial z} S_{iy}; \quad (4)$$

which, because of the spin dependent sign in Eq. 3, is proportional to the *spin* current $j_s = p j_c = 2e$ where j_c is the usual *charge* current. This key result for $p = 1$, has been derived from the double exchange model, as described in the methods section. This is also consistent with the Slonczewski (*I*) coupling proportional to $j S_i \cdot \mathbf{S}_{i+1} \cdot S_i$ where i and $i+1$ are adjacent sites in the direction of the current flow and with the approach of Bazaliy et al (*10*).

In order to correctly describe the motion of a Bloch wall it is necessary to first identify its center of mass momentum p_z and hence its position operator \hat{z}_0 . These involve the Goldstone boson b_w^y , mentioned above, and which is defined by considering a simple infinite wire with translational invariance, i.e., by definition, without any applied fields or forces. The momentum is the generator of displacements. The product of small y -axis rotations $R(\phi) = \exp(i \phi \sum_i (S_{iy} - S_{i+1,y}))$ ($\phi = a \int_{-\infty}^z S_{iy} dz$) $(1 + (1/2) \sum_i (\partial \phi_i / \partial z) z (2S)^{1/2} (b_i^y - b_{i+1}^y))$, produces a translation by z and the momentum, per atom in a plane of the wall, is identified as $p_z = \hbar (1/2) (v_c / a A_0) \sum_i (\partial \phi_i / \partial z) (2S)^{1/2} (b_i^y - b_{i+1}^y)$. This defines the Goldstone boson (2)

$$b_w^y = \frac{J}{8A} \sum_i \frac{v_c}{a A_0} \left(\frac{\partial \phi_i}{\partial z} \right) a b_i^y; \quad (5)$$

where the constant of proportionality reflects the requirement that $[b_w, b_w^y] = 1$ and uses the explicit wall solution for $\phi(z)$ given above. Thus $\hat{p}_z = \hbar \frac{2A}{J} \sum_i (2S)^{1/2} (1/a) (b_i^y - b_{i+1}^y)$ while the conjugate coordinate, such that $[\hat{z}_0, \hat{p}_z] = i\hbar$, is $\hat{z}_0 = a \frac{J}{2A} \sum_i (S=2)^{1/2} (b_w^y + b_w)$.

By definition, when a pressure P_z acts on the wall, H contains a term,

$$H_P = \frac{P_z v_c}{a} \hat{z}_0; \quad (6)$$

i.e., a term proportional to the wall coordinate operator \hat{z}_0 . From classical considerations it would be expected that

$$P_z = -\frac{a}{v_c} \frac{\partial V}{\partial z_0} \quad (7)$$

where $V(z_0)$ is the classical energy *per site* of a wall at position z_0 . That Eq. 7 gives the value of P_z appropriate to Eq. 6 follows from the result $\frac{\partial V}{\partial z_0} = \frac{i}{\hbar} [H; \hat{p}_z]$ of footnote (11). The only relevant term $[H_P; \hat{p}_z] = \frac{P_z v_c}{a} [\hat{z}_0; \hat{p}_z] = i\hbar \frac{P_z v_c}{a}$ to give Eq. 7. It can be verified directly that a z-directed applied field B generates a contribution of the form of Eq. 6 with $P_z = S g_B B = v_c$ and that this is the classically defined pressure. It is an important observation that a pressure *of any origin* is equivalent to that due to an applied magnetic field B and so in general the Eq. 2 becomes

$$E = P \frac{P_z v_c}{2eS}; \quad (8)$$

i.e., is determined by the *total* pressure P_z .

The wall is rendered stationary using two time dependent rotations generated by $r_i = e^{iS_{iz} \hat{z}_i t}$ and $r_i = e^{iS_{iy} \hat{y}_i(t)}$. The effect of passing to a rotating frame via r_i is to add an effective magnetic field $B_i = \hbar \hat{z}_i g_B$ directed along the axis of rotation (8). This is used to eliminate the explicit z-axis pressure P_z , i.e.,

$$\hbar \hat{z}_i = \hbar \frac{\partial}{\partial t} = \frac{P_z v_c}{2S}; \quad (9)$$

This predicts that the wall makes propellor rotations about the z axis. (To this must be added a z-axis oscillation when a perpendicular anisotropy is added. The effects of Gilbert relaxation are discussed below.) That there is no static classical solution when P_z is finite follows using the adaptation $\frac{\partial V}{\partial z_i} = \frac{i}{\hbar} [H; (S_{iz} = \hbar)]$ of footnote (11). Substituting the operators \hat{z}_0 and b_w^y into

Eq. 6 shows $H_p = \frac{P}{C_1} (\alpha_1^y + b_1)$, i.e., is *linear* in the b_1 . Since $(S_{iy} = \hbar) = (1=2i) (2S)^{1=2} (\alpha_1^y - b_1)$ it follows that $\frac{\partial V}{\partial i} = (1=\hbar) (2S)^{1=2} C_1 / P_z$. A static solution is not possible since this requires $(\partial V / \partial i) = 0$.

The interaction H_{ts} , which amounts to a field along the y -direction, is similarly rendered null via $r_i = e^{iS_{iy} - i(t)}$. That the wall is uniformly displaced implies $i = (z - z_0(t))$ where $z_0(t)$ is the time dependent position of the wall center. Differentiation with respect to time, defining the wall velocity $v = dz_0(t)/dt$, then implies

$$\frac{\partial i}{\partial t} = v \frac{\partial i}{\partial z} : \quad (10)$$

Thus the effective field which results from the time dependent $r_i = e^{iS_{iy} - i(t)}$ produces a term $\hbar v \frac{\partial i}{\partial z}$ which cancels H_{ts} when $v = pja^3 = 2eS$. This agrees with Eq. 2, obtained using the angular momentum conservation and confirms that H_{ts} correctly embodies this conservation principle.

Traditionally (6) relaxation is reflected by a Gilbert term $(=S) \mathcal{S}_i$ ($\mathcal{S}_i = \partial t$) which modifies $\mathcal{B}_i \rightarrow \mathcal{B}_i - (=S) \mathcal{B}_i$ ($\mathcal{S}_i = \partial t$) the internal magnetic field seen by spin i . However the additional fields *move with the wall* and cannot contribute to P_z , Eq. 7. This leaves Eq. 9 unchanged. In addition $(\mathcal{S}_i = \partial t)$ and the new \mathcal{B}_i lie in the wall plane and Eq. 10 is *also* unchanged. Dissipation, in addition to that in the load, occurs through forces acting on the electrons and is reflected by a reduction of the emf E . The Gilbert parameter for Permalloy 0.01 is the fraction of the energy lost in reversing a single spin. Since E is a similarly defined work, it is implied that E is reduced very little due to internal relaxation.

It is necessary to confirm Eq. 8 for the emf E . The adiabatic condition implies the spin and charge currents have the *fixed* relationship $j_s = pj_e = 2e$ and this permits Eq. 4 to be viewed as a *spin-charge* coupling via a vector potential $A_z^e = (p=e) (1=2S) (\partial = \partial z) \mathcal{S}_i$ and which gives the force on a charge carrier via $f_{zs}^e = (\partial A_z^e / \partial t)$. With the wall at the origin, for short

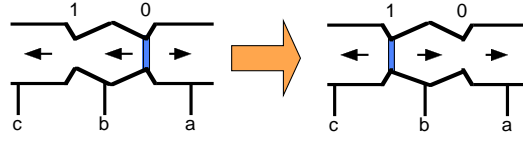


Figure 2: A current only read-write memory element. To the left the system is in the 0-state. A current between a and b will carry the wall past the unstable equilibrium point. As it moves towards 1-state under the force P_z implicit in the device shape it will produce an output emf between b and c. No emf occurs if the system is in the 1-state. The system can be switched between 0 and 1 by a passing a current from a to c.

times, $S_y = hS \sin \theta \sin \theta + \dots = S \sin \theta \sin \theta$. Thus $f_{zs} = (p-e) (1=2S) (\partial \theta / \partial z) \sin \theta \sin \theta = (p-e) (1=2) (\partial \cos \theta / \partial z) (P_z v_c = 2S)$ using Eq. 9. The work done is obtained by integrating this. The result is Eq. 8.

The predicted current densities j are very large. With $S = 1$ and $a = 3 \text{ \AA}$ and a realistic $(3) v = 1 \text{ m/s}$ the current density $j = 3 \cdot 10^6 \text{ A/m}^2$ or a current $i = 30 \text{ mA}$ for a micron square wire. The value of E reflects the value of B and for 1 T corresponding to about 100 V .

A basic memory device is illustrated in Fig. 2. The Boch wall has two stable equilibrium positions 0 and 1 and might be switched from one to the other using an external current. In a current only design, the device might be read by applying a current between a and b. If the wall lies in position 0 it will be dislodged by this reading pulse, and once it passes the half-way point, will induce an output in the circuit connecting b and c. Clearly, there will be no such current pulse if the wall is initially in position 1. Here the pressure P_z is produced by the shape of the bridge. (Instead the device might be read by simply applying a magnetic de-pinning field. The device will only produce a output pulse when the field has the correct sense to de-pin 0 rather than 1.) There are any number of other variants too numerous to be described here.

Current and power amplification might be achieved by the device shown in Fig. 3. Now only one of the equilibrium situations 0 is a truly stable. An initialization pulse latches the system in the unstable equilibrium position 1. A small short current pulse between a and b causes the

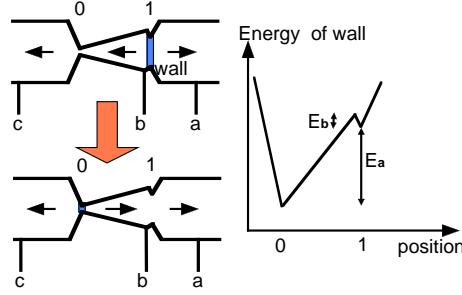


Figure 3: An power amplifier. Starting with the initial state, top left, a current pulse between a and b moves the wall from 1 to 0, i.e., a point at which there is a P_z to the left. There is an emf between b and c as the wall moves between b and 0. The final state is shown at the bottom left. To the right is shown the energy profile of the device, see text.

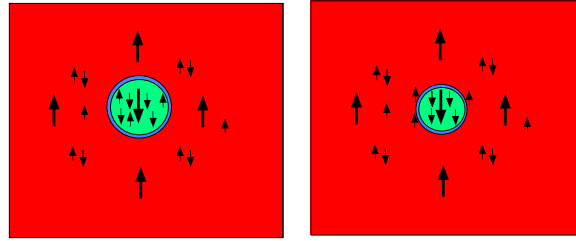


Figure 4: A spin sieve. The ferromagnetic state is indicated by the large spins. The small spins correspond to the itinerant electrons. The wall shown in blue has an energy proportional to its volume, i.e., there is a surface tension which would cause the bubble to collapse. This finite force P_z causes an smf between the interior and exterior so that the up, but not the down spins flow to the outside. This causes the bubble to get smaller and to have an interior with only down spins.

wall to leave 1 and the large P_z implicit in the design produces an equally large induced emf and hence a large current output in that part of the circuit which is connect to b and c. Isolation of input and output is afforded by the small distance 1 to b. The potential seen by the wall is also illustrated in Fig. 3. A large gain implies a small barrier, of height E_b , at an energy E_a relative to 0, and which is large compared to E_b . In fact, the power gain g is limited by, and is approximately equal to, $g = \frac{E_a}{E_b}$; since the input pulse must raise the wall over the barrier, i.e., give it an energy E_a while the maximum energy which is given to the external output circuit is evidently E_a . In position 1 the wall might either tunnel or be thermally excited out of this

unstable equilibrium, *however* the wall constitutes a macroscopic object and this affords and enormous reduction in both of these processes. For the sake of illustration imagine the depinning field is 0.01T or 0.01K . If the wire has 10^8 atoms in both perpendicular directions there are 10^6 spins in the cross-section and, for a wall with a length of $w = 10^8$ spins, it is implied that the barrier height is $10^9 = 0.01 = 10\text{K}$ which precludes the possibility of direct escape by both thermal excitation and tunneling.

Finally, there is an interesting field theory aspect to the problem. The aligned local moment ferromagnetic state defines an essentially featureless vacuum. The present system has two such vacuo connected by a solitonic object, namely the Bloch wall. When acted upon by a force, the wall can *only* move when there is an appropriate itinerant electron spin current. In fact, the wall acts as a “spin sieve” causing up and down spins to move in opposite directions. In the geometry shown in Fig. 4 the wall wishes to collapse under the force of its own surface tension but cannot unless it pumps up spins outwards. A similar situation is possible in which the magnetic broken symmetry is replaced by that associated with *any* quantum number. If this was, e.g., the quantum number which distinguishes particles from anti-particles the sieve would separate matter from anti-matter.

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9. Using that $\hbar S_{iz} \rightarrow S_{iz}$ upon dropping the spin wave operators b_i^y and b_i .
10. Ya. B. Bazaliy, B. A. Jones, and Shou-Cheng Zhang, Phys. Rev. **B57**, R3213 (1998)
11. If z_0 is a coordinate, then it is a general result for the classical ground state energy $V_f(z_0)$, defined earlier in the text, that, $\frac{\partial V}{\partial z_0} = \frac{i}{\hbar} [H; \hat{p}_z]$ where \hat{p}_z is the generator of translations and only the non-operator, i.e., c-number, part of commutator is retained. This might be applied directly to the wall coordinate z_0 where \hat{p}_z is given in the text, or for a rotation by θ , if $z_0 \rightarrow z_0 + \theta$ and $\hat{p}_z \rightarrow S_{iz} = \hbar \left(\frac{n-2i}{2} \right) (b_i^y - b_i)$. The proof: the energy change $V = R^{-1} H R$ where $R = 1 + i(\hat{p}_z = \hbar) z$, where by definition V is the c-number part of the right hand side. This becomes $V = R^{-1} [H; R] = [H; R]$ since $R^{-1} \rightarrow 1$ as $z \rightarrow 0$. Then $V = (i\hbar) [H; \hat{p}_z] z$ to yield the sought after result.
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Supplementary material

Methods

The microscopic theory is based upon a standard model for ferromagnets, i.e., the double exchange model:

$$\begin{aligned}
 H = & \sum_{\langle ij \rangle} t \sum_{\sigma} c_{i\sigma}^{\dagger} c_{j\sigma} + H_{\text{ex}} + U \sum_i n_{i\uparrow} n_{i\downarrow} \\
 & + \sum_i (J_0 \mathbf{S}_i \cdot \mathbf{S}_{i\#} + A S_{iz}^2) + \sum_{\langle ij \rangle} J_{ij}^0 \mathbf{S}_i \cdot \mathbf{S}_j \\
 & + 2 \sum_i \mu_B H (S_{iz} + \frac{1}{2} \sum_{\sigma} c_{i\sigma}^{\dagger} c_{i\sigma}) \quad \hat{N}
 \end{aligned} \tag{S1}$$

where \mathbf{S}_i is the spin operator and $c_{i\sigma}^{\dagger}$ creates an electron with spin σ at site i . The wire extends along the z -direction which, with $A > 0$, is the easy axis. The chemical potential is μ and \hat{N} is the total number operator. For simplicity only a single chain is considered and the lattice spacing is denoted by a .

The problem is treated in the half metal limit when the onsite $|J_0| \gg t$. Since physically $|J_0| < U$ it is also implied that $U \gg t$ and which corresponds to highly correlated electrons. This permits(2) a spinless majority electron operator $c_{i\uparrow}^{\dagger} = c_{i\uparrow}^{\dagger}$ to be defined, and in terms of this, the minority $c_{i\downarrow}^{\dagger} = s_i c_{i\uparrow}^{\dagger}$ where s_i is the conduction electron spin lowering operator. For large J_0 only the largest total angular momentum manifold is relevant. At a site occupied by a conduction electron, only states with $J = S + 1 = 2$ need to be accounted for and it follows(2) that $s_i = S_i = (2S)$. Physically this implies that the conduction electrons pass adiabatically through the wall, i.e., the system always stays close to the ground state, as discussed in the text. This is *not* an assumption about local equilibrium of the conduction electrons but rather is an immediate and *rigorous* consequence of the Wigner-Eckart theorem. With this the conduction spin degrees of freedom are sub-summed into those which describe the local moments. In this limit there is

a separation of the spin and charge degrees of freedom. The charge sector is spanned by the states created by the spinless fermions c_i^y , while S_i is the unique spin vector.

As outlined in the Report, the Holstein-Primakoff transformation $S_{iz} = S - b_i^\dagger b_i$, $S_i^+ = (2S - b_i^\dagger b_i)^{1/2} b_i$, $(2S)^{1/2} b_i$ is used to quantize the spins. The local axis of quantization is specified by the Euler angles θ_i and ϕ_i . In order that the resulting magnon energies are positive definite, it is necessary that these angles correspond to the *classical* equilibrium direction. When substituted into H the coefficient of higher order interactions decreases by a factor of $(2S)^{1/2}$ for each additional b_i^\dagger or b_i . It follows that this approach generates an expansion in $1/S$ about the classical solution.

It is important to understand the role of the contacts in relation to conservation of the angular momentum S_z . In the absence of contacts, $[S_z, H] = 0$, so that $S_z = 0$ and the wall cannot move. It is *wrong* to conclude that this fact reflects an infinite mass. Observe, when the surface integral $\int_{\mathcal{S}} \mathbf{j}_s \cdot \mathbf{A} \neq 0$, where \mathbf{j}_s is the *spin* current density, it *must* be the case that in the local equation for dS_i/dt there is a term $\propto \mathbf{j}_s / s_i$ which couples this current to the spin dynamics. This is the H_{ts} discussed in the Report and below. In the half metal limit assumed in this microscopic theory $\mathbf{j}_s = \mathbf{j}_e$ the charge current density.

In the absence of a wall, for large U , the kinetic energy term is $\hat{T} = \sum_{ij} t_{ij} (c_i^y c_j + s_i c_i^y c_j s_j^+) + H_{\text{ex}}$. Following the text, the Bloch wall is generated via a (SU(2)) gauge transformation of the conduction electrons. Since there is a single conduction electron fermion this simplifies to the top entry in the conduction electron spinor:

$$c_j^y \rightarrow e^{i s_{iy}} c_j^y \quad (S2)$$

Then $e^{i s_{iy}} = e^{i (\theta_i/2) \phi_{iy}} = \cos(\theta_i/2) + i \sin(\theta_i/2) \phi_{iy}$ since $\phi_{iy}^2 = 1$. Finally $\phi_{iy} = i(\phi_i^+ - \phi_i^-)$ and since $s_i^+ c_j^y \rightarrow 0$ it follows that

$$c_i^y \rightarrow (\cos[\theta_i/2] + \sin[\theta_i/2] s_i) c_i^y \quad (S3)$$

This and its Hermitean conjugate are substituted into the kinetic energy to give:

$$\hat{T} = \sum_{ij} \frac{\hbar^2}{2m} \cos[(\mathbf{k}_i - \mathbf{k}_j) \cdot \mathbf{r}_{ij}] (c_i^\dagger c_j + s_i c_i^\dagger c_j s_j^\dagger) + \sum_{ij} \frac{\hbar^2}{2m} \sin[(\mathbf{k}_i - \mathbf{k}_j) \cdot \mathbf{r}_{ij}] (s_i c_i^\dagger c_j - c_i^\dagger c_j s_j^\dagger) + H_{\text{sc}} \quad (\text{S } 4)$$

Charge motion arises principally via $H_t = \sum_{ij} t_{ij} c_i^\dagger c_j + H_{\text{sc}}$ where $t_{ij} = t \cos[(\mathbf{k}_i - \mathbf{k}_j) \cdot \mathbf{r}_{ij}]$. The reduction of t_{ij} in the Bloch wall represents a barrier, however this has a height $\sim SA$ which in reality is quite negligible compared to the Fermi energy E_F . The solutions of H_t are, to a good approximation, plain \mathbf{k} -states independent of the wall position or its motion. There can be no “spin-accumulation” of conduction electrons around the wall.

The current-spin interaction arises from the part of \hat{T} which is linear in s_i . Using the adiabatic condition $\mathbf{s} = S\hat{\mathbf{z}}$, the relevant interaction is:

$$H_{ts} = \frac{\hbar^2}{2(2S)^{1/2}} \frac{\partial}{\partial z} a \sum_i c_{i+1}^\dagger c_i (\mathbf{b}_i \cdot \mathbf{b}_{i+1}^\dagger) + H_{\text{sc}} \quad (\text{S } 5)$$

where $(\mathbf{k}_i - \mathbf{k}_{i+1}) \cdot \mathbf{r}_{i+1} = (\partial/\partial z)a$ has been used and which assumes that the wall width $w \ll a$. Current carrying eigenstates are also eigenstates of $\hat{n}_k = c_k^\dagger c_k$ the number operator. When acting on such a state the spin-charge interaction reduces to

$$H_{ts} = \frac{\hbar^2 a^2}{2eS} \frac{\partial}{\partial z} a (2S)^{1/2} (\mathbf{b}_1 \cdot \mathbf{b}_1^\dagger) \quad (\text{S } 6)$$

Here $(2S)^{1/2} (1/2i) (\mathbf{b}_1 \cdot \mathbf{b}_1^\dagger) = S_y'$ defined to be strictly perpendicular to the *instantaneous* axis of quantization. This constitutes an explicit derivation of the key Eqn. 3 of the Report albeit for the limit $p = 1$.

The, bi-linear in s_i , part of \hat{T} is also of importance. When acting on eigenstates of H_t these lead to a renormalization, $J_{ij} = J_{ij}^0 + (\hbar^2 t^2 / 2S^2)$, of the total inter-site exchange coupling J_{ij} . The effective concentration $x^0 = \hbar^2 t^2 / 2S^2$. One of the interests in the spintronics field is the possibility of exerting forces on, and pinning of, a Bloch wall. The presence of x^0 in the expression for J_{ij} indicates that this potentially can be modified and modulated dynamically in a field effect device.